# Low Voltage Single Supply SPDT Analog Switch

The NLAS4599 is an advanced high speed CMOS single pole – double throw analog switch fabricated with silicon gate CMOS technology. It achieves high speed propagation delays and low ON resistances while maintaining low power dissipation. This switch controls analog and digital voltages that may vary across the full power–supply range (from  $V_{CC}$  to GND).

The device has been designed so the ON resistance  $(R_{ON})$  is much lower and more linear over input voltage than  $R_{ON}$  of typical CMOS analog switches.

The channel select input is compatible with standard CMOS outputs.

The channel select input structure provides protection when voltages between 0 V and 5.5 V are applied, regardless of the supply voltage. This input structure helps prevent device destruction caused by supply voltage – input/output voltage mismatch, battery backup, hot insertion, etc.

- Channel Select Input Over-Voltage Tolerant to 5.5 V
- Fast Switching and Propagation Speeds
- Break-Before-Make Circuitry
- Low Power Dissipation:  $I_{CC} = 2 \mu A$  (Max) at  $T_A = 25^{\circ}C$
- Diode Protection Provided on Channel Select Input
- Improved Linearity and Lower ON Resistance over Input Voltage
- Latch-up Performance Exceeds 300 mA
- ESD Performance: Human Body Model > 2000 V; Machine Model > 200 V
- Chip Complexity: 38 FETs
- Pb-Free Packages are Available

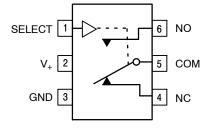


Figure 1. Pin Assignment

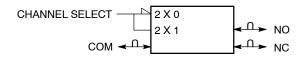


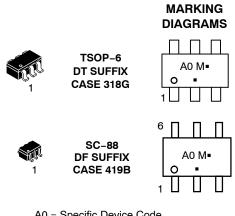
Figure 2. Logic Symbol

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



## **ON Semiconductor®**

http://onsemi.com



A0 = Specific Device Code M = Date Code • = Pb-Free Package (Note: Microdot may be in either location)

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

#### **FUNCTION TABLE**

Select	ON Channel
L	NC
Н	NO

### **ABSOLUTE MAXIMUM RATINGS**

Symbol		Parameter	Value	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	9	-0.5 to +7.0	V
V <sub>IS</sub>	Analog Input Voltage (V <sub>NO</sub>	or V <sub>COM</sub> )	$-0.5 \le V_{IS} \le V_{CC} + 0.5$	V
V <sub>IN</sub>	Digital Select Input Voltage		$-0.5 \leq V_{l} \leq +\ 7.0$	V
I <sub>IK</sub>	DC Current, Into or Out of	Any Pin	±50	mA
P <sub>D</sub>	Power Dissipation in Still A	ir SC-88 TSOP-6	200 200	mW
T <sub>STG</sub>	Storage Temperature Rang	-65 to +150	°C	
TL	Lead Temperature, 1mm fr	om Case for 10 seconds	260	°C
TJ	Junction Temperature Und	er Bias	150	°C
V <sub>ESD</sub>	ESD Withstand Voltage	Human Body Model (Note 1) Machine Model (Note 2) Charged Device Model (Note 3)	2000 200 N/A	V
I <sub>LATCH-UP</sub>	Latch-Up Performance	Above $V_{CC}$ and Below GND at 125°C (Note 4)	± 300	mA
$\theta_{JA}$	Thermal Resistance	SC-88 TSOP-6	333 333	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Tested to EIA/JESD22-A114-A

2. Tested to EIA/JESD22-A115-A

3. Tested to JESD22-C101-A

4. Tested to EIA/JESD78

### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Characteristic	Min	Max	Unit	
V <sub>CC</sub>	DC Supply Voltage		2.0	5.5	V
V <sub>IN</sub>	Digital Select Input Voltage	GND	5.5	V	
V <sub>IS</sub>	Analog Input Voltage (NC, NO, COM)	GND	V <sub>CC</sub>	V	
T <sub>A</sub>	Operating Temperature Range		-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise or Fall Time, SELECT	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0	100 20	ns/V

#### DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

Junction Temperature °C	Time, Hours	Time, Years
80	1,032,200	117.8
90	419,300	47.9
100	178,700	20.4
110	79,600	9.4
120	37,000	4.2
130	17,800	2.0
140	8,900	1.0

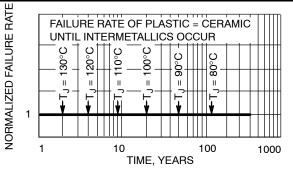


Figure 3. Failure Rate vs. Time Junction Temperature

				Gua			
Symbol	Parameter	Condition	V <sub>cc</sub>	-55 to 25°C	<85°C	<125°C	Unit
VIH	Minimum High–Level		2.0	1.5	1.5	1.5	V
	Input Voltage, Select		2.5	1.9	1.9	1.9	
	Input		3.0	2.1	2.1	2.1	
			4.5	3.15	3.15	3.15	
			5.5	3.85	3.85	3.85	
V <sub>IL</sub>	Maximum Low-Level		2.0	0.5	0.5	0.5	V
	Input Voltage, Select		2.5	0.6	0.6	0.6	
	Input		3.0	0.9	0.9	0.9	
			4.5	1.35	1.35	1.35	
			5.5	1.65	1.65	1.65	
I <sub>IN</sub>	Maximum Input Leakage Current, Select Input	V <sub>IN</sub> = 5.5 V or GND	5.5	<u>+</u> 0.1	<u>+</u> 1.0	<u>+</u> 1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or GND	0	±10	±10	±10	μΑ
I <sub>CC</sub>	Maximum Quiescent Supply Current	Select and $V_{IS} = V_{CC}$ or GND	5.5	1.0	1.0	2.0	μΑ

### DC CHARACTERISTICS - Digital Section (Voltages Referenced to GND)

# DC ELECTRICAL CHARACTERISTICS – Analog Section

				Gua	aranteed Lin	nit	
Symbol	Parameter	Condition	V <sub>CC</sub>	–55 to 25°C	<85°C	<125°C	Unit
R <sub>ON</sub>	Maximum "ON"	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub>	2.5	85	95	105	Ω
	Resistance	$V_{IS} = GND$ to $V_{CC}$	3.0	45	50	55	
	(Figures 17 – 23)	l <sub>IN</sub> I <u>≤</u> 10.0 mA	4.5	30	35	40	
			5.5	25	30	35	
R <sub>FLAT</sub> (ON)	ON Resistance Flatness (Figures 17 – 23)	$\label{eq:VIN} \begin{split} V_{IN} &= V_{IL} \text{ or } V_{IH} \\ I_{IN} I &\leq 10.0 \text{ mA} \\ V_{IS} &= 1V, 2V, 3.5V \end{split}$	4.5	4	4	5	Ω
ΔR <sub>ON</sub> (ON)	ON Resistance Match Between Channels	$\label{eq:VIN} \begin{split} V_{IN} &= V_{IL} \text{ or } V_{IH} \\ I_{IN}I &\leq 10.0 \text{ mA} \\ V_{NO} \text{ or } V_{NC} &= 3.5 \text{ V} \end{split}$	4.5	2	2	3	Ω
I <sub>NC(OFF)</sub> I <sub>NO(OFF)</sub>	NO or NC Off Leakage Current (Figure 9)		5.5	1	10	100	nA
I <sub>COM(ON</sub> )	COM ON Leakage Current (Figure 9)	$\label{eq:VIN} \begin{split} V_{IN} &= V_{IL} \text{ or } V_{IH} \\ V_{NO} \ 1.0 \ V \text{ or } 4.5 \ V \text{ with } V_{NC} \\ \text{floating or} \\ V_{NO} \ 1.0 \ V \text{ or } 4.5 \ V \text{ with } V_{NO} \\ \text{floating} \\ V_{COM} &= 1.0 \ V \text{ or } 4.5 \ V \end{split}$	5.5	1	10	100	nA

### **AC ELECTRICAL CHARACTERISTICS** (Input $t_r = t_f = 3.0 \text{ ns}$ )

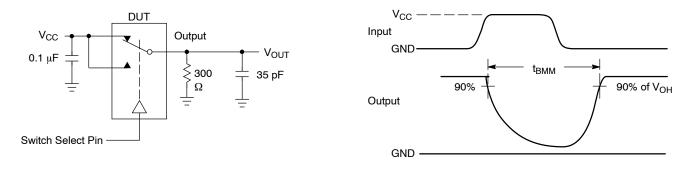
					Guaranteed Max Limit			t				
			$v_{cc}$	VIS	-5	i5 to 25	°C	<85	5°C	<125°C		
Symbol	Parameter	Test Conditions	(V)	(V)	Min	Тур*	Max	Min	Max	Min	Max	Unit
t <sub>ON</sub>	Turn-On Time (Figures 12 and 13)	$R_L$ = 300 $\Omega,C_L$ = 35 pF (Figures 5 and 6)	2.5 3.0 4.5 5.5	2.0 2.0 3.0 3.0	5 5 2 2	23 16 11 9	28 21 16 14	5 5 2 2	30 25 20 20	5 5 2 2	30 25 20 20	ns
t <sub>OFF</sub>	Turn-Off Time (Figures 12 and 13)	$R_L$ = 300 $\Omega,C_L$ = 35 pF (Figures 5 and 6)	2.5 3.0 4.5 5.5	2.0 2.0 3.0 3.0	1 1 1 1	7 5 4 3	12 10 9 8	1 1 1 1	15 15 12 12	1 1 1 1	15 15 12 12	ns
t <sub>BBM</sub>	Minimum Break-Before-Make Time	$V_{IS}$ = 3.0 V (Figure 4) R <sub>L</sub> = 300 $\Omega$ , C <sub>L</sub> = 35 pF	2.5 3.0 4.5 5.5	2.0 2.0 3.0 3.0	1 1 1	12 11 6 5		1 1 1		1 1 1 1		ns

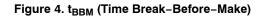
\*Typical Characteristics are at 25°C.

		Typical @ 25, VCC = 5.0 V	
$\begin{array}{c} C_{IN} \\ C_{NO} \text{ or } C_{NC} \\ C_{COM} \\ C_{(ON)} \end{array}$	Maximum Input Capacitance, Select Input Analog I/O (switch off) Common I/O (switch off) Feedthrough (switch on)	8 10 10 20	pF

### ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

			v <sub>cc</sub>	Typical	
Symbol	Parameter	Condition	(Ň)	25°C	Unit
BW	Maximum On–Channel –3dB Bandwidth or Minimum Frequency Response (Figure 10)	$V_{IN} = 0 \text{ dBm}$ $V_{IN}$ centered between $V_{CC}$ and GND (Figure 7)	3.0 4.5 5.5	170 200 200	MHz
V <sub>ONL</sub>	Maximum Feedthrough On Loss	$V_{IN}$ = 0 dBm @ 100 kHz to 50 MHz $V_{IN}$ centered between $V_{CC}$ and GND (Figure 7)	3.0 4.5 5.5	-3 -3 -3	dB
V <sub>ISO</sub>	Off-Channel Isolation (Figure 10)	$f$ = 100 kHz; $V_{IS}$ = 1 V RMS $V_{IN}$ centered between $V_{CC}$ and GND (Figure 7)	3.0 4.5 5.5	-93 -93 -93	dB
Q	Charge Injection Select Input to Common I/O (Figure 15)	$ \begin{array}{l} V_{IN} = V_{CC \ to} \ GND, \ F_{IS} = 20 \ \text{kHz} \\ t_r = t_f = 3 \ \text{ns} \\ R_{IS} = 0 \ \Omega, \ C_L = 1000 \ \text{pF} \\ Q = C_L \ast \Delta V_{OUT} \\ (Figure \ 8) \end{array} $	3.0 5.5	1.5 3.0	рC
THD	Total Harmonic Distortion THD + Noise (Figure 14)	$F_{IS}$ = 20 Hz to 100 kHz, $R_L$ = Rgen = 600 $\Omega,$ $C_L$ = 50 pF $V_{IS}$ = 5.0 $V_{PP}$ sine wave	5.5	0.1	%





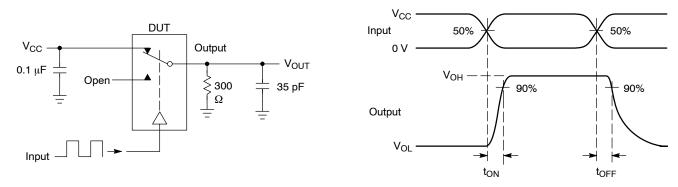
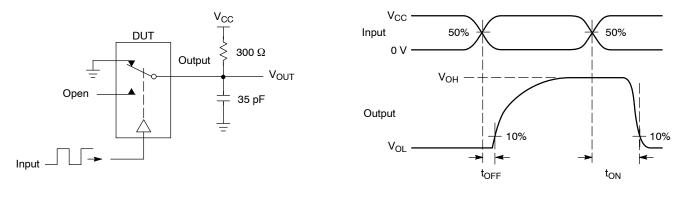
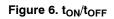
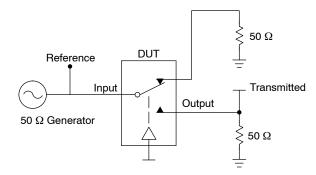


Figure 5. t<sub>ON</sub>/t<sub>OFF</sub>



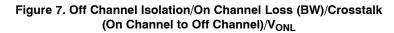


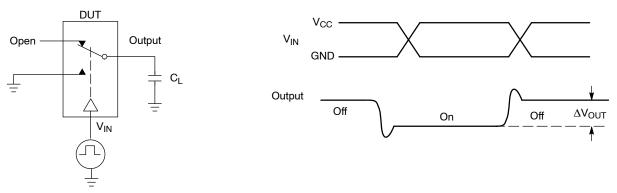


Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch.  $V_{ISO}$ , Bandwidth and  $V_{ONL}$  are independent of the input signal direction.

$$\begin{split} V_{ISO} &= \text{Off Channel Isolation} = 20 \text{ Log } \left( \frac{V_{OUT}}{V_{IN}} \right) \text{ for } V_{IN} \text{ at } 100 \text{ kHz} \\ V_{ONL} &= \text{On Channel Loss} = 20 \text{ Log } \left( \frac{V_{OUT}}{V_{IN}} \right) \text{ for } V_{IN} \text{ at } 100 \text{ kHz} \text{ to } 50 \text{ MHz} \end{split}$$

Bandwidth (BW) = the frequency 3 dB below  $V_{ONL}$ 







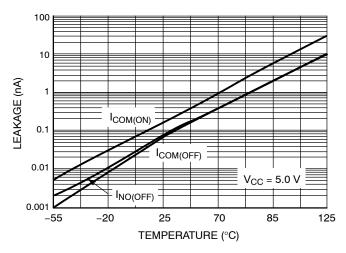
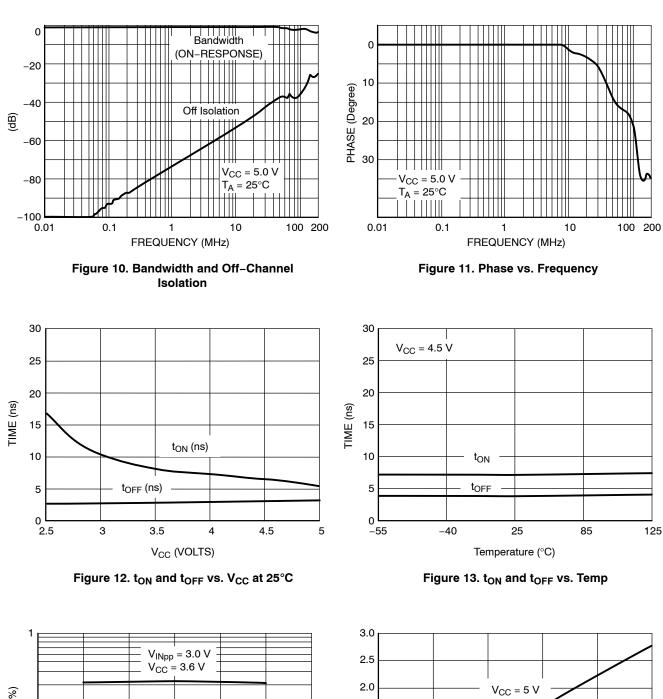
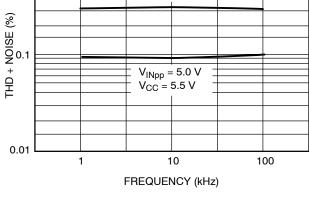
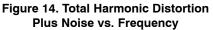
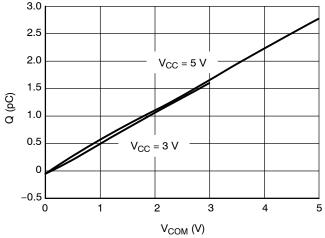


Figure 9. Switch Leakage vs. Temperature

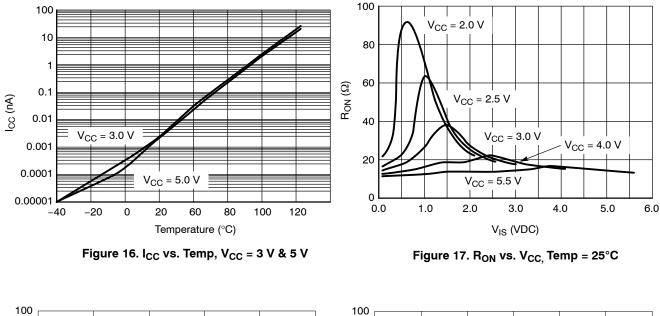


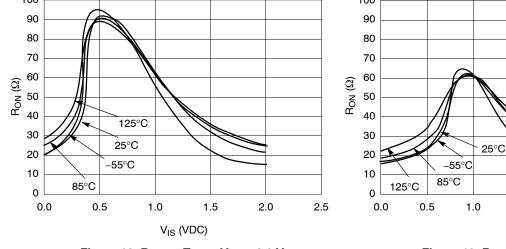














50

45

40 35

30

25

20

15

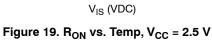
10

5

0

0.0

Ron (Q)

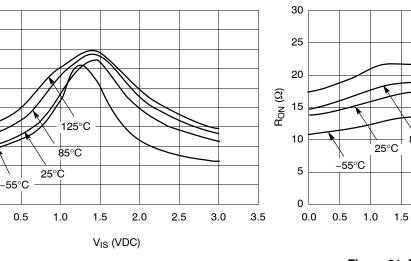


1.5

2.0

2.5

3.0



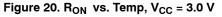


Figure 21. R<sub>ON</sub> vs. Temp,  $V_{CC}$  = 4.5 V

V<sub>IS</sub> (VDC)

125°C

2.5

3.0

3.5

4.0

4.5

85°C

2.0

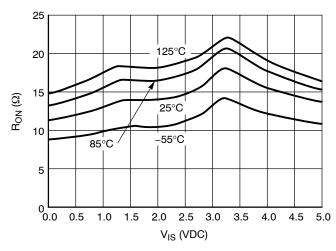


Figure 22. R<sub>ON</sub> vs. Temp,  $V_{CC}$  = 5.0 V

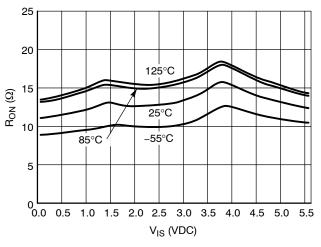


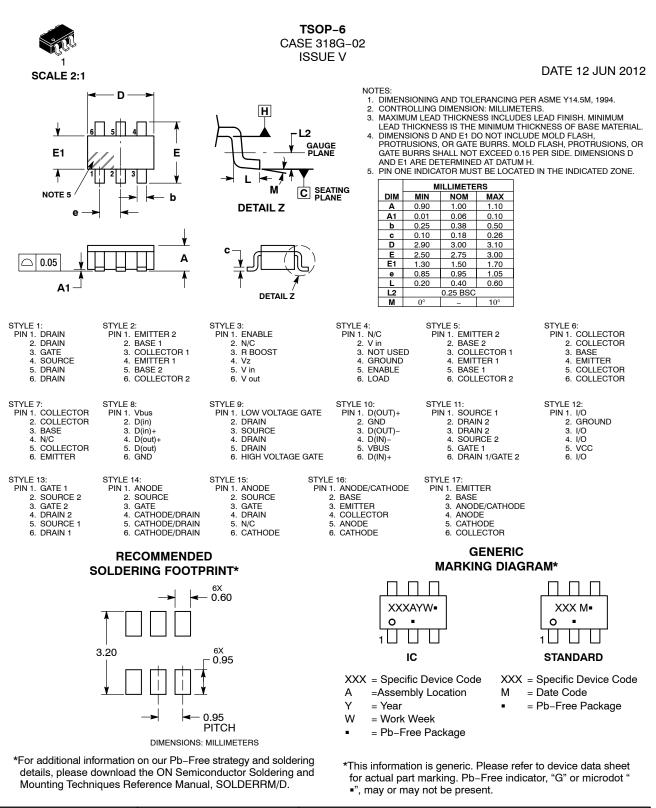
Figure 23. R<sub>ON</sub> vs. Temp,  $V_{CC}$  = 5.5 V

#### **ORDERING INFORMATION**

		Device Nom	nenclature			
Device	Circuit Indicator	Technology	Device Function	Suffix	Package	Shipping <sup>†</sup>
NLAS4599DFT2	NL	AS	DF	T2	SC-88	3000 / Tape & Reel
NLAS4599DFT2G	NL	AS	DF	T2G	SC-88 (Pb-Free)	3000 / Tape & Reel
NLAS4599DTT1	NL	AS	DT	T1	TSOP-6	3000 / Tape & Reel
NLAS4599DTT1G	NL	AS	DT	T1G	TSOP-6 (Pb-Free)	3000 / Tape & Reel
NLVAS4599DFT2	NL	AS	DF	T2	SC-88	3000 / Tape & Reel
NLVAS4599DFT2G	NL	AS	DF	T2G	SC-88 (Pb-Free)	3000 / Tape & Reel
NLVAS4599DTT1G	NL	AS	DT	T1G	TSOP-6 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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0.043

0.004





- XXX = Specific Device Code

(Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering

details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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#### SC-88/SC70-6/SOT-363 CASE 419B-02 ISSUE Y

### DATE 11 DEC 2012

STYLE 1: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. COLLECTOR 4. EMITTER 5. BASE 6. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE	STYLE 6: PIN 1. ANODE 2 2. N/C 3. CATHODE 1 4. ANODE 1 5. N/C 6. CATHODE 2
STYLE 7: PIN 1. SOURCE 2 2. DRAIN 2 3. GATE 1 4. SOURCE 1 5. DRAIN 1 6. GATE 2	STYLE 8: CANCELLED	STYLE 9: PIN 1. EMITTER 2 2. EMITTER 1 3. COLLECTOR 1 4. BASE 1 5. BASE 2 6. COLLECTOR 2	STYLE 10: PIN 1. SOURCE 2 2. SOURCE 1 3. GATE 1 4. DRAIN 1 5. DRAIN 2 6. GATE 2	STYLE 11: PIN 1. CATHODE 2 2. CATHODE 2 3. ANODE 1 4. CATHODE 1 5. CATHODE 1 6. ANODE 2	STYLE 12: PIN 1. ANODE 2 2. ANODE 2 3. CATHODE 1 4. ANODE 1 5. ANODE 1 6. CATHODE 2
STYLE 13:	STYLE 14:	STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:
PIN 1. ANODE	PIN 1. VREF	PIN 1. ANODE 1	PIN 1. BASE 1	PIN 1. BASE 1	PIN 1. VIN1
2. N/C	2. GND	2. ANODE 2	2. EMITTER 2	2. EMITTER 1	2. VCC
3. COLLECTOR	3. GND	3. ANODE 3	3. COLLECTOR 2	3. COLLECTOR 2	3. VOUT2
4. EMITTER	4. IOUT	4. CATHODE 3	4. BASE 2	4. BASE 2	4. VIN2
5. BASE	5. VEN	5. CATHODE 2	5. EMITTER 1	5. EMITTER 2	5. GND
6. CATHODE	6. VCC	6. CATHODE 1	6. COLLECTOR 1	6. COLLECTOR 1	6. VOUT1
STYLE 19:	STYLE 20:	STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:
PIN 1. I OUT	PIN 1. COLLECTOR	PIN 1. ANODE 1	PIN 1. D1 (i)	PIN 1. Vn	PIN 1. CATHODE
2. GND	2. COLLECTOR	2. N/C	2. GND	2. CH1	2. ANODE
3. GND	3. BASE	3. ANODE 2	3. D2 (i)	3. Vp	3. CATHODE
4. V CC	4. EMITTER	4. CATHODE 2	4. D2 (c)	4. N/C	4. CATHODE
5. V EN	5. COLLECTOR	5. N/C	5. VBUS	5. CH2	5. CATHODE
6. V REF	6. COLLECTOR	6. CATHODE 1	6. D1 (c)	6. N/C	6. CATHODE
STYLE 25:	STYLE 26:	STYLE 27:	STYLE 28:	STYLE 29:	STYLE 30:
PIN 1. BASE 1	PIN 1. SOURCE 1	PIN 1. BASE 2	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. SOURCE 1
2. CATHODE	2. GATE 1	2. BASE 1	2. DRAIN	2. ANODE	2. DRAIN 2
3. COLLECTOR 2	3. DRAIN 2	3. COLLECTOR 1	3. GATE	3. COLLECTOR	3. DRAIN 2
4. BASE 2	4. SOURCE 2	4. EMITTER 1	4. SOURCE	4. EMITTER	4. SOURCE 2
5. EMITTER	5. GATE 2	5. EMITTER 2	5. DRAIN	5. BASE/ANODE	5. GATE 1
6. COLLECTOR 1	6. DRAIN 1	6. COLLECTOR 2	6. DRAIN	6. CATHODE	6. DRAIN 1

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

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